

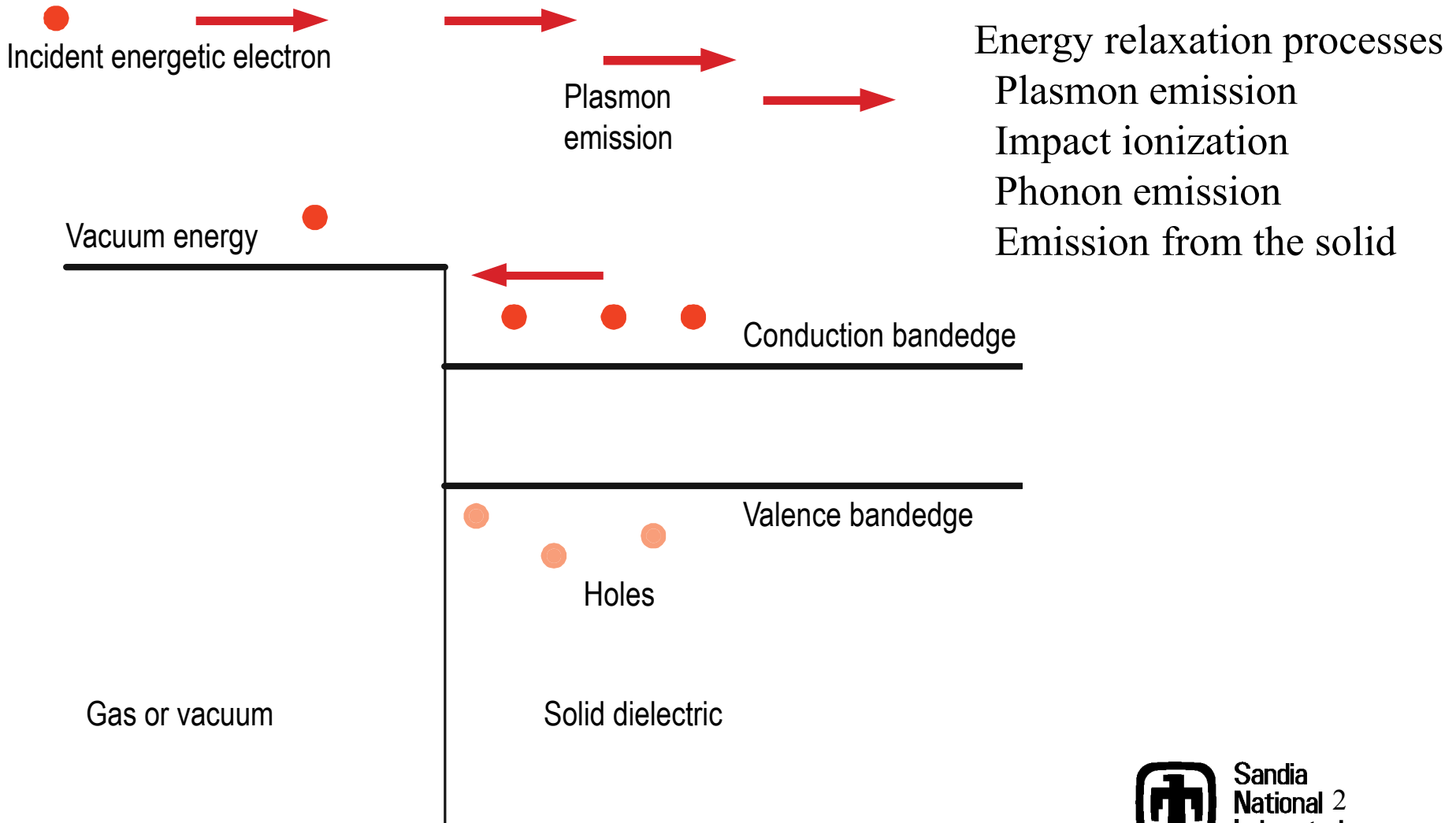
Secondary Electron Emission (SEE)^{SAND2012-1452C} Calculations

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Secondary Electron Emission (SEE): Basic Phenomena



Outline

- **Basic Phenomena**
- **Motivation**
 - Low energy radiation transport
 - Electrical breakdown at rutile surfaces
- **Monte Carlo Calculations**
 - Method
 - Results
- **Continuum Radiation Effects in Oxides and Semiconductors (REOS) Calculations**
 - Method
 - Results
- **Why Use Two Methods?**
 - More insights are possible
 - A Monte Carlo method to link to radiation transport
 - A continuum method to link to thermal breakdown physics



Experimental Results: Yield Curve

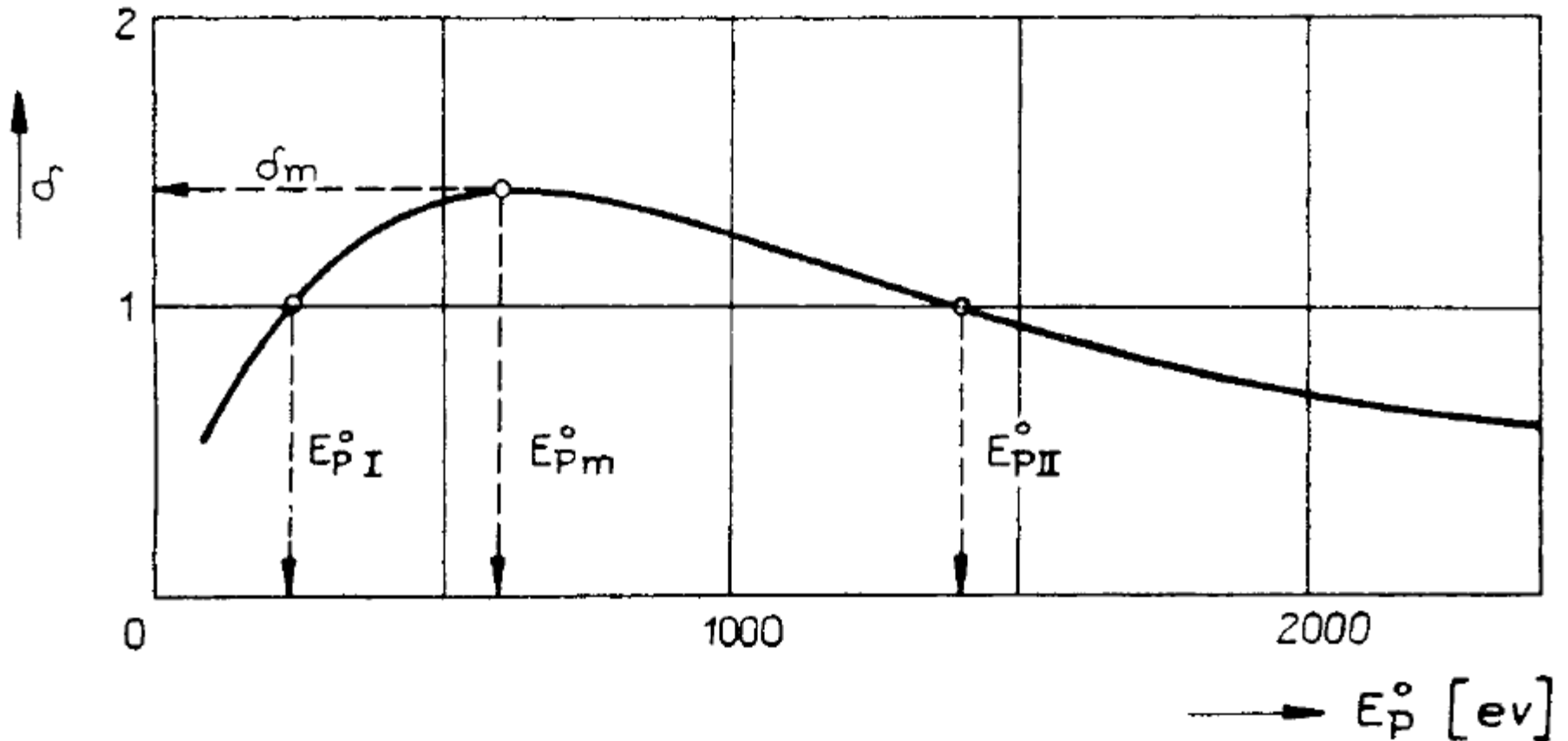


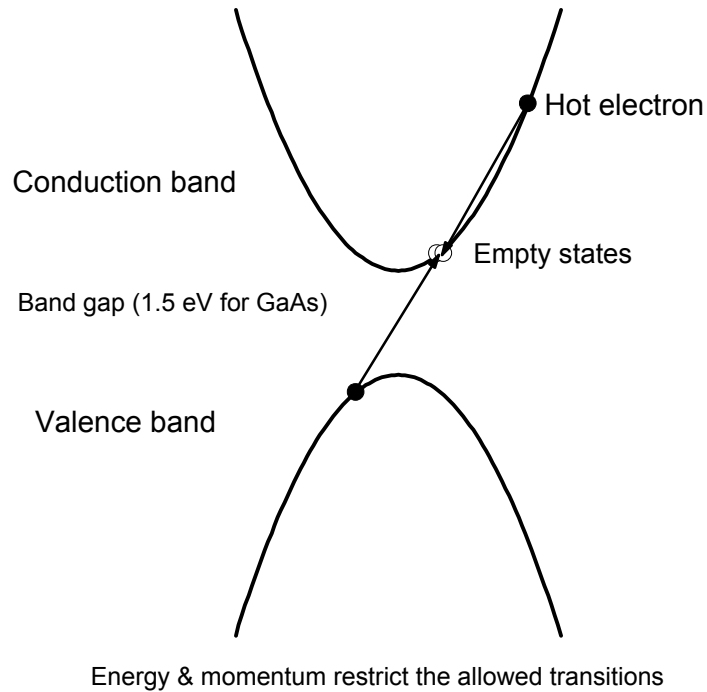
FIG. 11. The general shape of the yield curve $\delta (E_p^\circ)$.

Monte Carlo Calculations

Procedure

- **Follow trajectory of an energetic electron as it enters the solid**
- **Allow free flights and scattering events**
- **Scattering events**
 - Plasmon emission
 - Impact ionization
 - Phonon scattering
 - Emission from the sample
- **Perform these calculations using an ensemble Monte Carlo method**
 - Use bandstructure
 - Use empirical scattering information

Evolution in Momentum Space (K-Space)



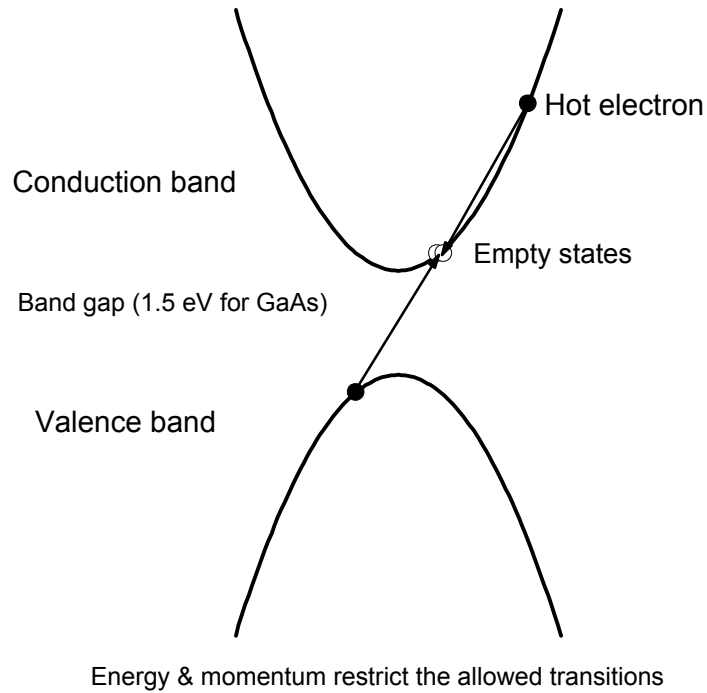
Newton's Laws

$$\frac{dk_z}{dt} = \frac{qF_z}{h}$$

$$\frac{dz}{dt} = \frac{hk_z}{m}$$

F = electric, q = electron charge, m = effective mass

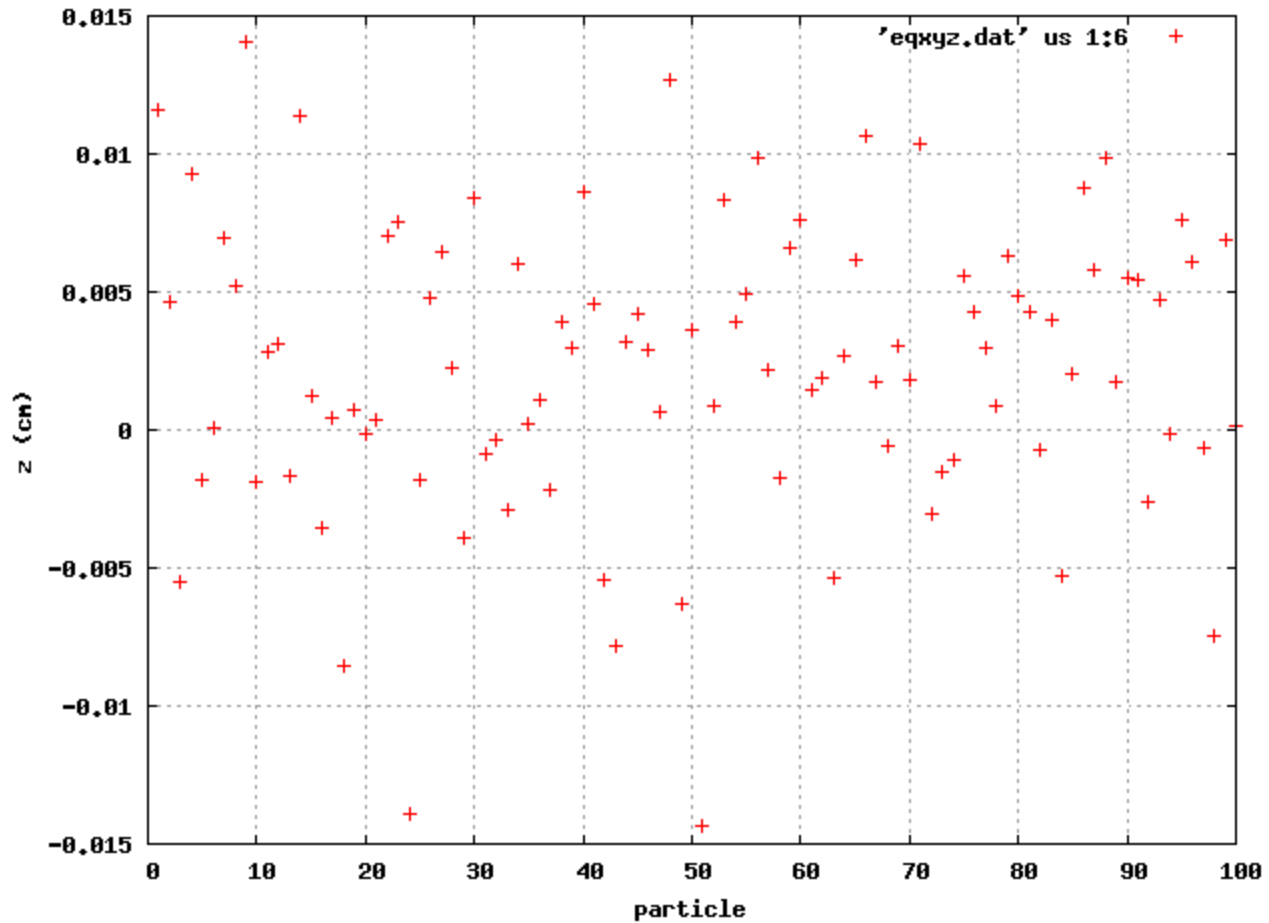
Impact Ionization



Monte Carlo Methods

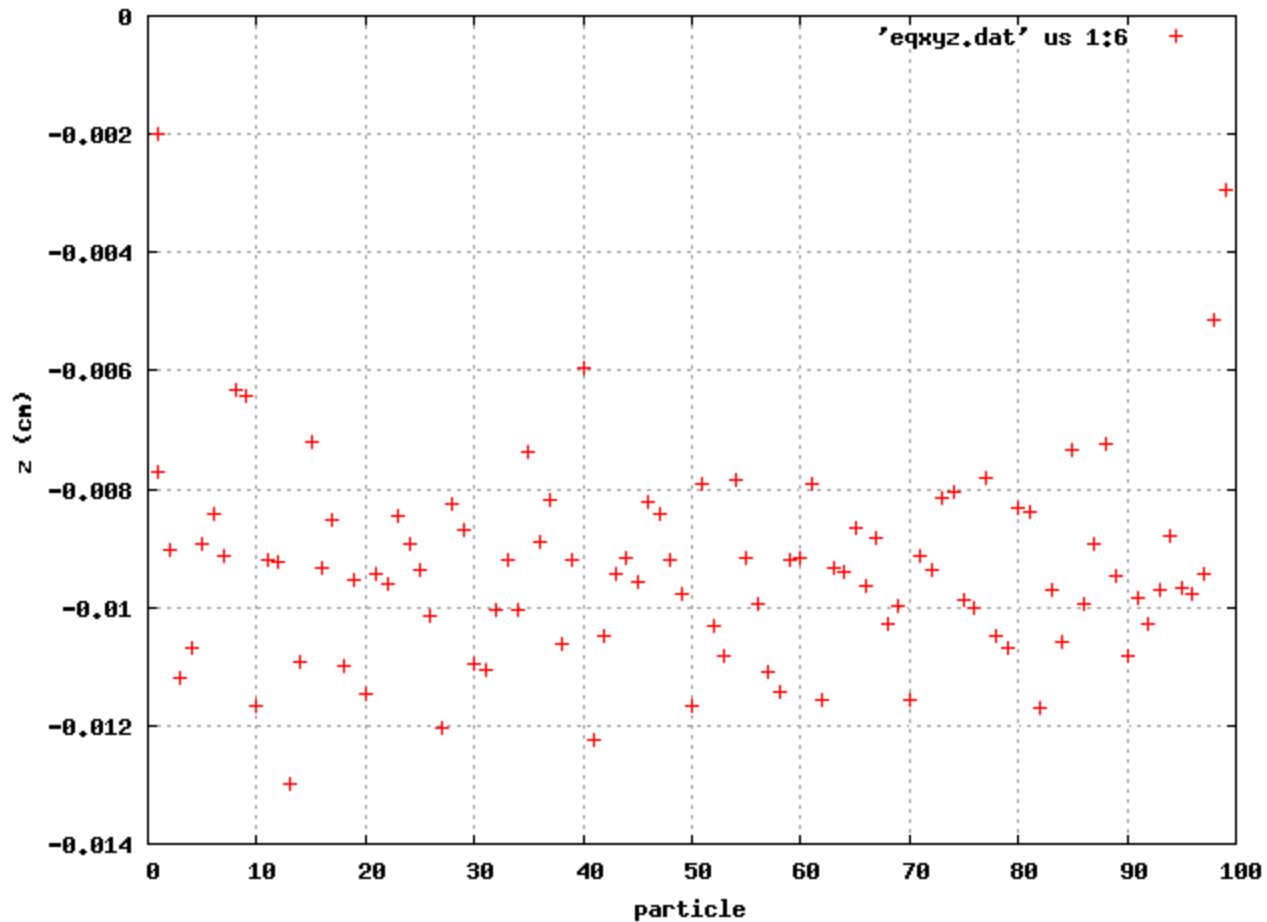
- **Simple Description**
 - “Free flight” of electrons and holes in momentum space (bandstructure)
 - **Scattering**
 - Impact ionization
 - Phonons
 - Emission from the sample (with no return)

Diffusion



Wed Dec 07 09:49:28 2011

Drift + Diffusion



Thu Dec 08 12:44:47 2011

Electron Emission: Monte Carlo Results

- **Undecided physics issue: the vacuum-solid interface**
 - One approach: an electric field over a small region
 - $qFd = \text{energy shift}$
 - Another approach: A hop to an energy-shifted bandstructure

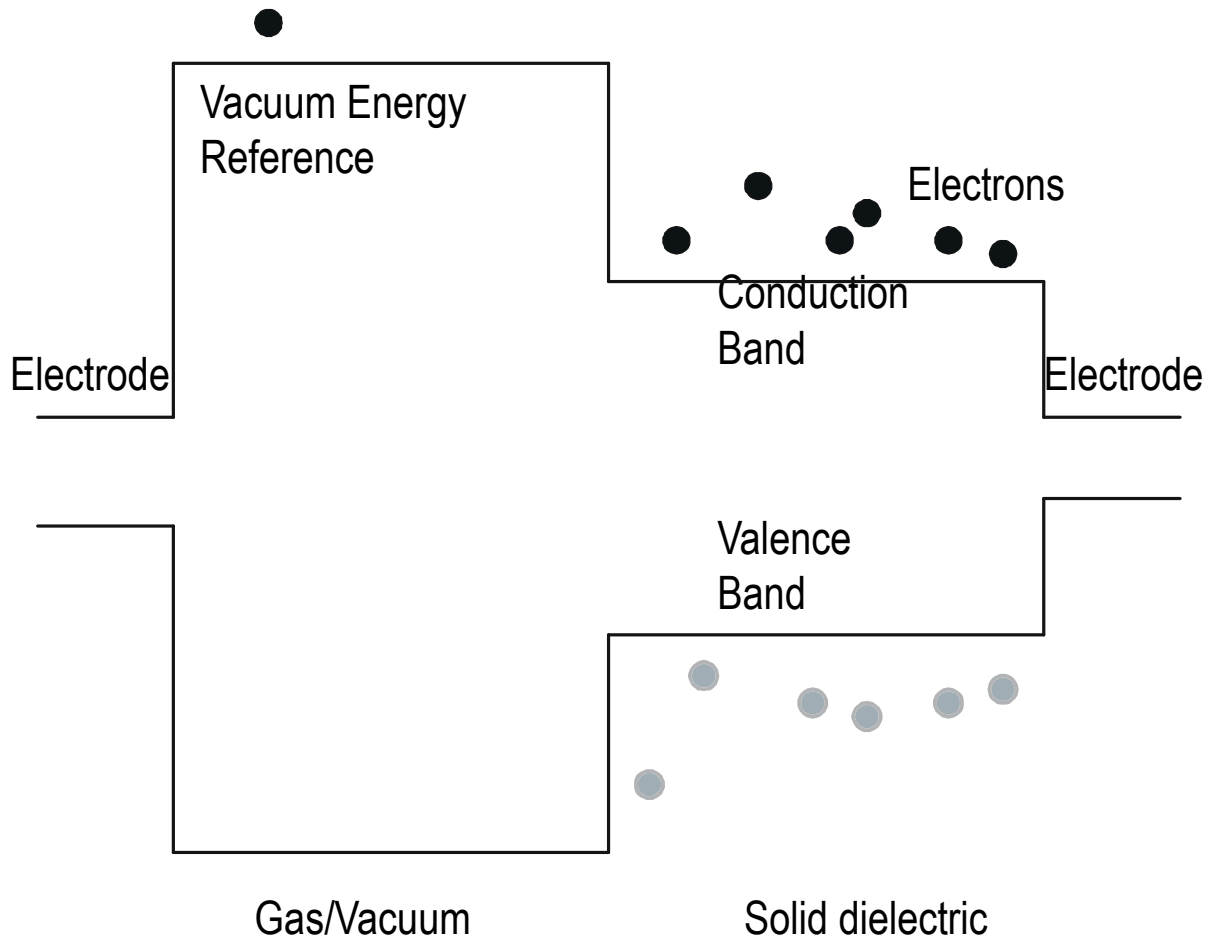
Continuum Calculations

Radiation Effects in Oxides and Semiconductors (REOS) Calculations

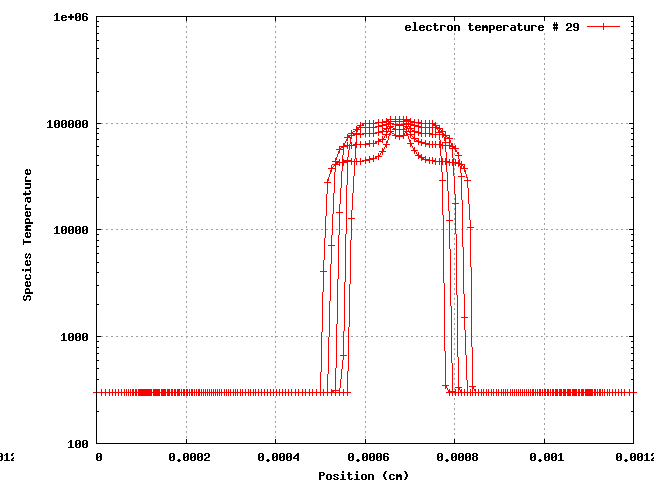
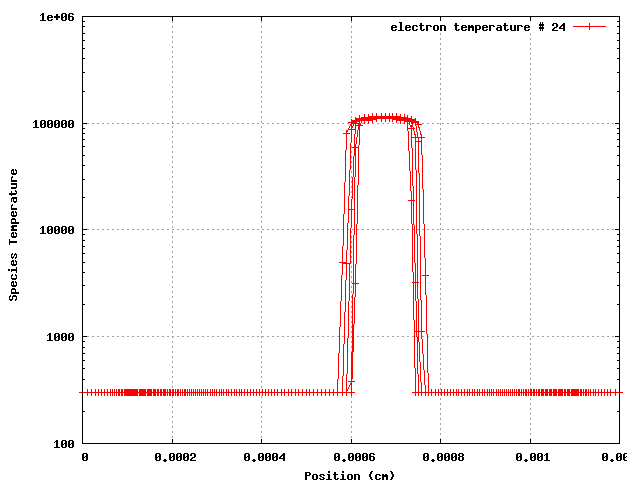
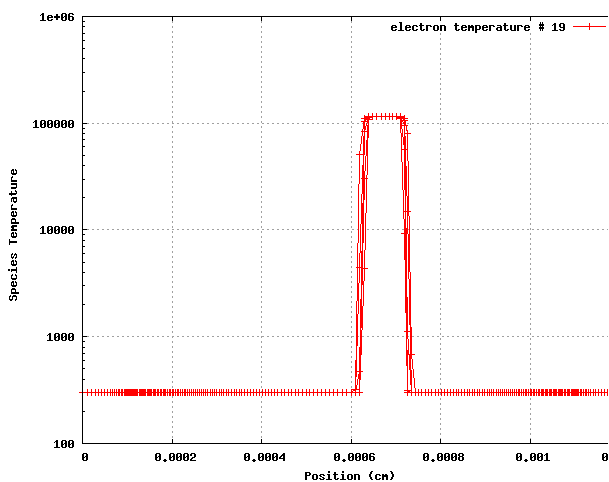
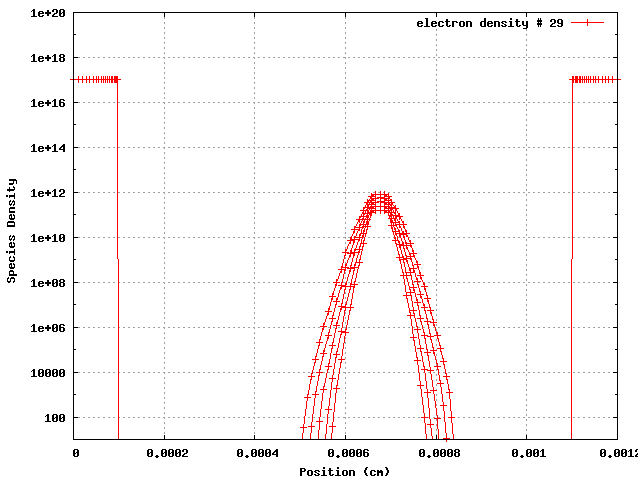
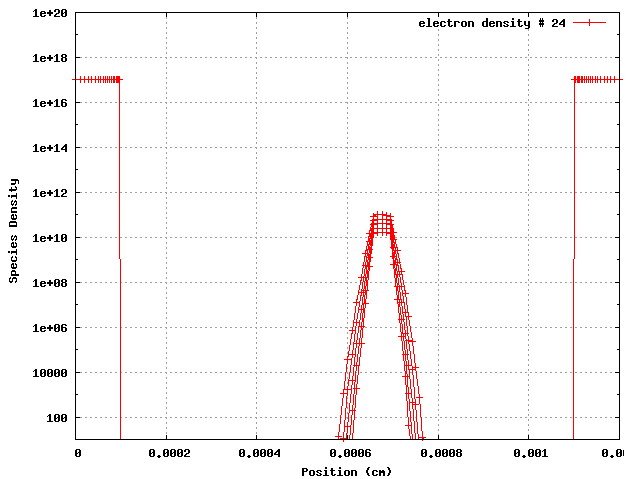
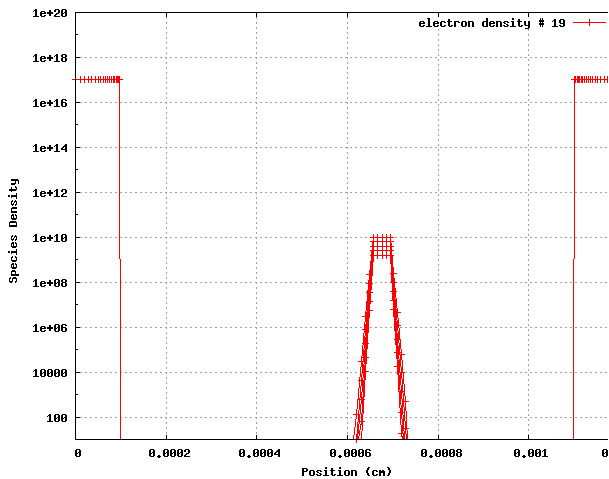
- **Features**
 - Transport
 - Energy relaxation
 - Chemical reactions
 - Heteromaterial interfaces
- **Emphasis**
 - Physics
 - Simple geometry
- **Method**
 - Inject electrons and holes in the RHS insulating region
 - Include energy relaxation processes that control the temperature
 - Follow evolution in space and temperature

SEE Calculations: Structure

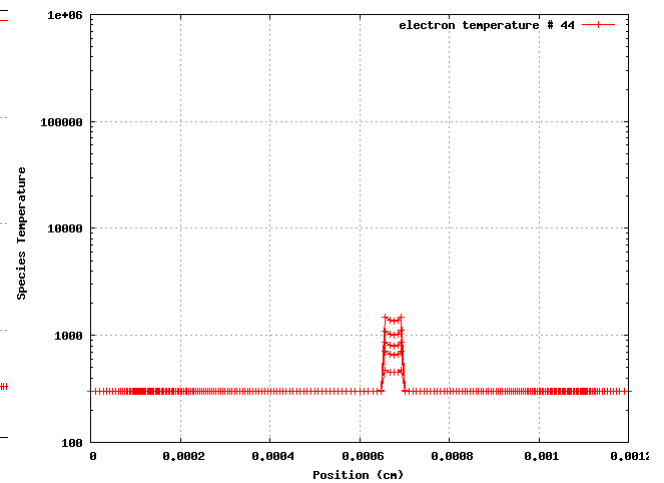
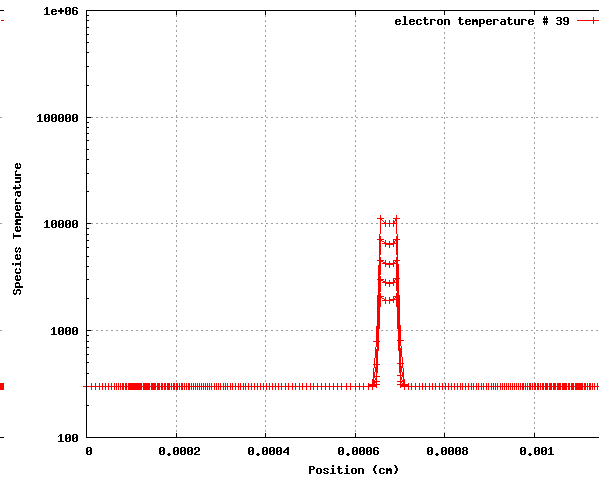
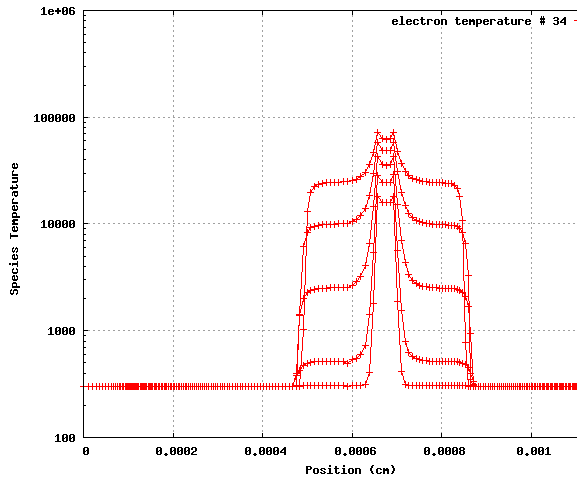
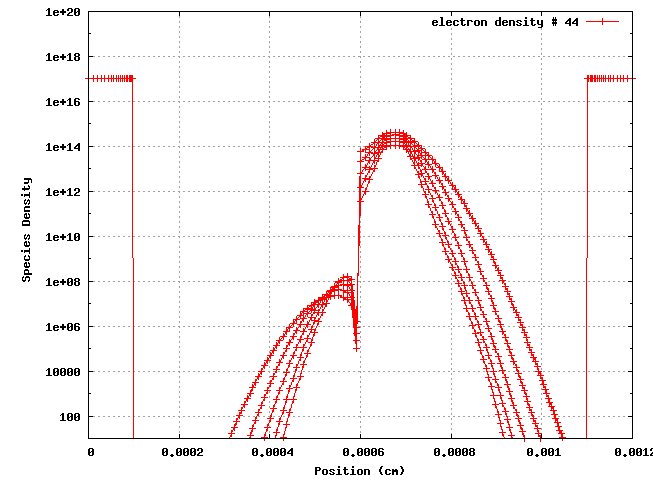
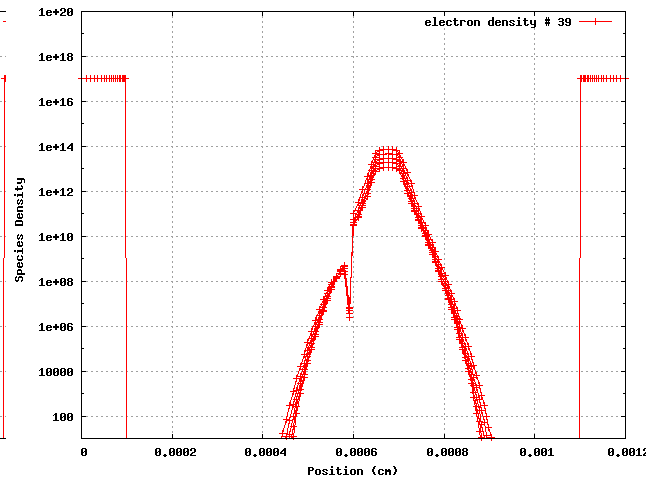
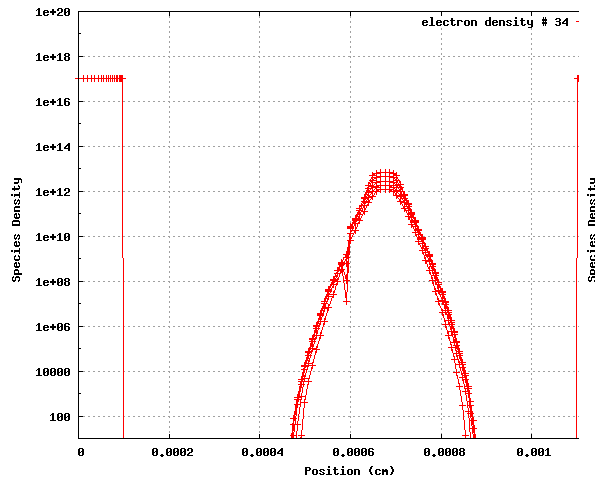
Metal-insulator-insulator-metal



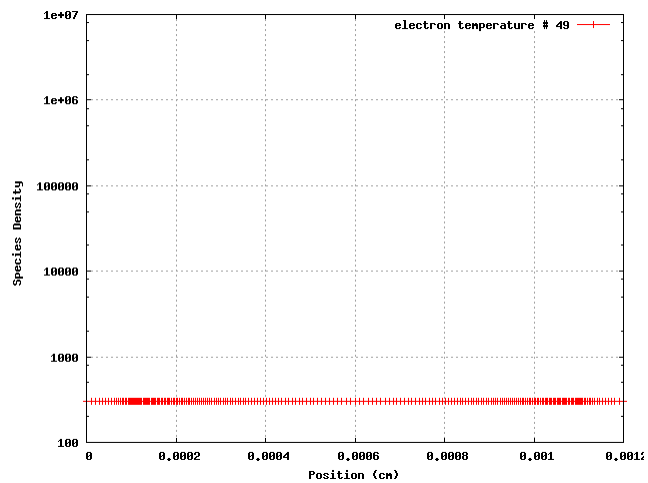
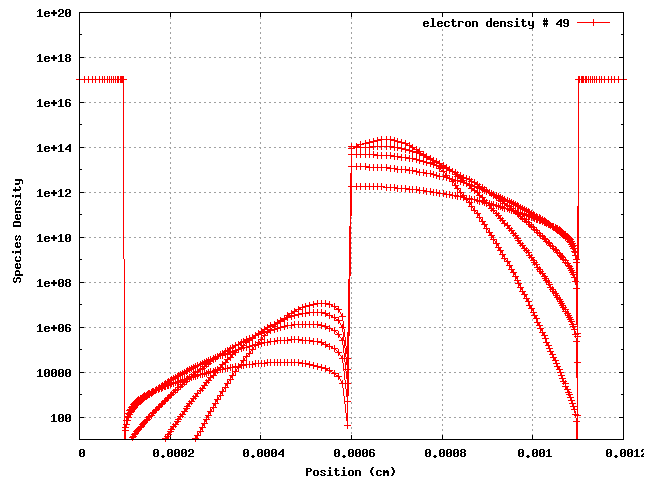
Electron Density and Temperature: 0.1 ps, 1 ps and 10 ps



Electron Density and Temperature: 100 ps, 1 ns and 10 ns



Electron Density and Temperature: 100 ns



Summary: Physics Insights

- **Energy deposition rate depends on charged particle velocity**
- **Cooling versus emission depends on bandgap versus affinity**

Low-Energy Radiation Transport LDRD

- **Secondary Electron Emission (SEE) is a good test problem**
 - Monte Carlo calculations
 - REOS calculations
- **Good results obtained**
 - SEE information needed for the LAC project
 - Will be presented at the APS meeting next week

Extra Slides